



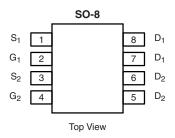
Dual P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
	0.021 at V _{GS} = - 4.5 V	- 8.0		
- 8	0.027 at V _{GS} = - 2.5 V	- 7.0		
	0.040 at V _{GS} = - 1.8 V	- 5.8		

FEATURES

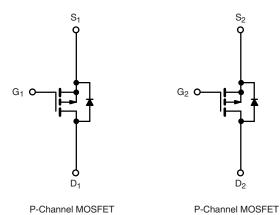
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs: 1.8 V Rated
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si4965DY-T1-E3 (Lead (Pb)-free)

Si4965DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS T	$A = 25 ^{\circ}C$, unles	ss otherwise n	oted	
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 8	V
Gate-Source Voltage		V_{GS}	± 8	v
Out! Durin Oursel /T 450 00/8 h	T _A = 25 °C		- 8.0	
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 70 °C	- I _D	- 6.4	
Pulsed Drain Current		I _{DM}	- 30	Α
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	- 1.7	
w · D D · · · ah	T _A = 25 °C	D	2.0	10/
Maximum Power Dissipation ^{a, b}	T _A = 70 °C	P _D	1.3	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	- R _{thJA}		62.5	°C/W	
	Steady State		93		- C/VV	

Notes:

a. Surface Mounted on FR4 board.

 $b.\ t \leq 10\ s.$

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	$V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$ - 0.45			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 8 V, V _{GS} = 0 V		- 1				
		$V_{DS} = -8 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			- 5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 20			Α		
		$V_{GS} = -4.5 \text{ V}, I_D = -8.0 \text{ A}$		0.0175	0.021	Ω		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 7.0 A		0.022	0.027			
		V _{GS} = - 1.8 V, I _D = - 5.8 A		0.031	0.040			
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_{D} = -8.0 \text{ A}$		27		S		
Diode Forward Voltage ^a	V_{SD}	$I_S = -1.7 \text{ A}, V_{GS} = 0 \text{ V}$			- 1.2	V		
Dynamic ^b								
Total Gate Charge	Q_g			36	55			
Gate-Source Charge	Q _{gs}	$V_{DS} = -4 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -8.0 \text{ A}$		7.5		nC		
Gate-Drain Charge	Q _{gd}			5.0				
Turn-On Delay Time	t _{d(on)}			35	70			
Rise Time	t _r	V_{DD} = - 4 V, R_L = 4 Ω		45	90			
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 4.5 V, R_g = 6 Ω		170	340	ns		
Fall Time	t _f			90	180			
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -1.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		60	90			

Notes:

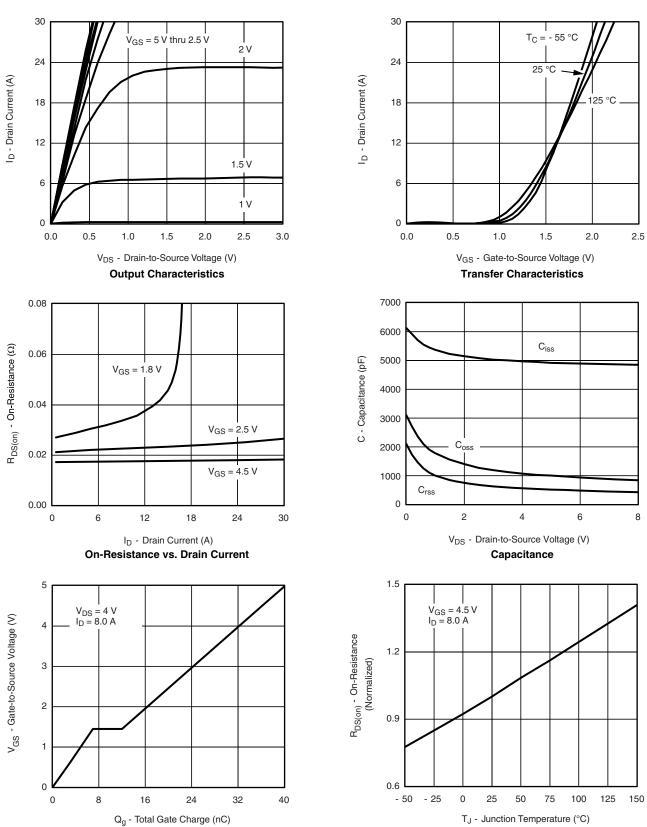
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



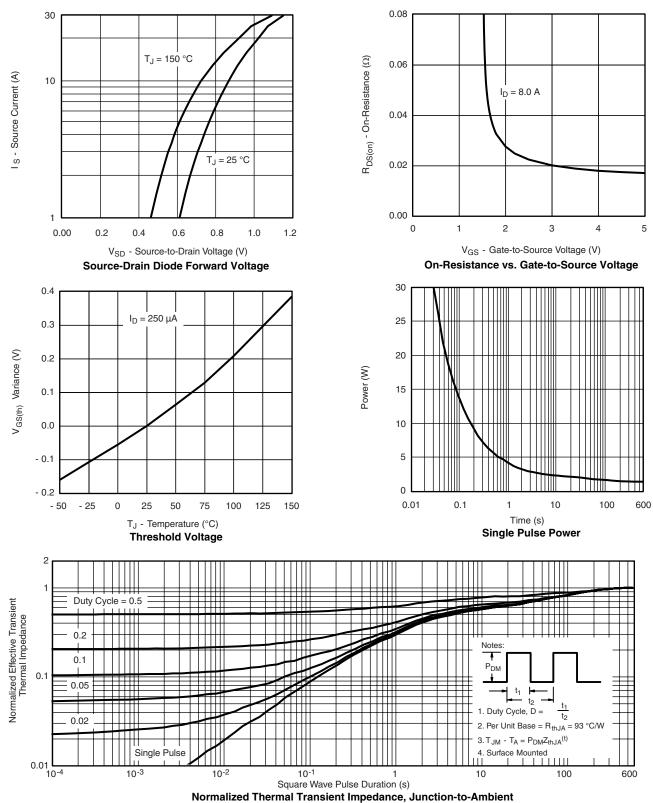
Gate Charge

On-Resistance vs. Junction Temperature

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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